

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.		FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/736,602 12/17/2003		12/17/2003	Michael A. Kneissl	115917	5826		
27074	7590	06/23/2006		EXAM	EXAMINER		
OLIFF & B		GE, PLC.	GOLUB, MARCIA A				
P.O. BOX 19928 ALEXANDRIA, VA 22320				ART UNIT	PAPER NUMBER		
				2828			
				DATE MAILED: 06/23/2006			

Please find below and/or attached an Office communication concerning this application or proceeding.

А	
H	•
lΛ	
•	

		Applicatio	n No.	Applicant(s)					
	Office Assistant Commencer	10/736,60	2	KNEISSL ET AL.					
	Office Action Summary	Examiner		Art Unit					
		Marcia A. 0		2828					
Period fo	The MAILING DATE of this communicated reply	ation appears on the	cover sheet with the c	orrespondence ad	ldress				
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).									
Status			,						
1)⊠	Responsive to communication(s) filed	on <u>06 June 2006</u> .							
<i>,</i> —	•) ☐ This action is n	on-final.						
3)	Since this application is in condition fo	r allowance except	for formal matters, pro	secution as to the	e merits is				
	closed in accordance with the practice	under <i>Ex parte Qu</i>	ayle, 1935 C.D. 11, 45	3 O.G. 213.					
Dispositi	Disposition of Claims								
4)🖾)⊠ Claim(s) <u>1-50</u> is/are pending in the application.								
	4a) Of the above claim(s) is/are withdrawn from consideration.								
5) 🗀	5) Claim(s) is/are allowed.								
6)⊠	Claim(s) <u>1-3,7,8,18-20.25,26,28-30</u> is/are rejected.								
•	Claim(s) is/are objected to.								
8)□	Claim(s) are subject to restriction	on and/or election re	equirement.						
Applicati	on Papers		٠						
, —	The specification is objected to by the								
10)	The drawing(s) filed on is/are: a								
	Applicant may not request that any objecti								
_	Replacement drawing sheet(s) including the								
11)	The oath or declaration is objected to t	by the Examiner. No	te the attached Office	Action or form P	10-152.				
Priority ι	ınder 35 U.S.C. § 119								
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). 									
* S	See the attached detailed Office action	for a list of the certi	fied copies not receive	ed.					
	e of References Cited (PTO-892)	4) Interview Summary							
2) Notice 3) Information	ce of Draftsperson's Patent Drawing Review (PT) mation Disclosure Statement(s) (PTO-1449 or P r No(s)/Mail Date		Paper No(s)/Mail Di 5) Notice of Informal P 6) Other:		O-152)				

Application/Control Number: 10/736,602

Art Unit: 2828

DETAILED ACTION

Response to Arguments

Applicant's arguments received on 6/6/06 have been considered but are moot in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-3, 7, 18, 19, 28 and 29 are rejected under 35 U.S.C. 103(a) as being unpatentable over McCall (5,343,490) hereinafter '490, and further in view of Kinoshita (6,330,265) hereinafter '265.

Regarding **claim 1**, Fig 8 of '490 disclose "a grating-outcoupled microcavity disk resonator [80], defining a plane [81, 82] and having a substantially smooth curved outer periphery [83] (9/55-56), bounded by reflective walls, around and within which light can circulate (3/36-38); the resonator including at least one grating region [84] disposed in the plane [81] of the grating-outcoupled microcavity disk resonator [80]; the grating region [84] serving to outcouple light circulating within the curved outer periphery into free space modes propagating out of the plane of the resonator." (11/22-23)

'490 does not disclose that the grating region "has a substantially symmetric profile". However, Fig 2a of '265 discloses a grating with a sawtooth profile located in the waveguide and cladding layers of the laser.

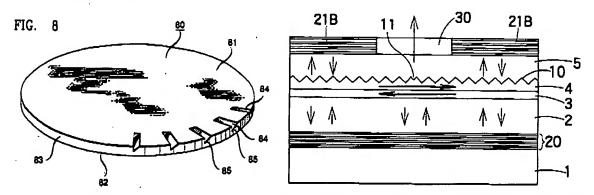
It would have been obvious to one of ordinary skill in the art at the time of the invention to incorporate the teachings of '265 into the device of '490 by making the grating with a sawtooth profile located in the waveguide and cladding layers for at least the purpose of outcoupling light circulating in both clockwise and counterclockwise directions.

Application/Control Number: 10/736,602

Art Unit: 2828

Regarding claims 2, 3, 7, 18, 19, 28 and 29, Fig 8 of '490 and Fig 2A of '265 disclose a grating-outcoupled microcavity disk resonator as described above:

- 2. "wherein the grating region [10] is a set of periodic features formed in or on a cladding layer [5] of the resonator."
- 3. "wherein the periodic features [10] have a sawtooth shape."
- 7. "wherein the grating region forms at least a second order grating." (title of Fig 2a)
- 18. "wherein the grating region [10] is a set of periodic features formed in an upper cladding layer [5] of the resonator."
- 19. "wherein the grating region [10] is formed in an upper cladding layer [5] and an upper waveguide layer [4] of the resonator."
- 28, 29. "wherein the grating-outcoupled cavity resonator comprises a heterostructure formed using at least one of InP (claim 28) and InGaAsP (claim 29)." (7/27-29 of '490)



Claim 8 is rejected under 35 U.S.C. 103(a) as being unpatentable over '490 and '265 as applied to claim 1 above, and further in view of Baird et al. (5,559,824) hereinafter '824.

Regarding **claim 8**, '490 and '265 disclose a grating-outcoupled microcavity disk resonator as described above, but do not disclose "that the grating region forms at least a distributed feedback grating."

However, DFB gratings in semiconductor lasers are well known in the art as evidenced by '824 (6/29-47).

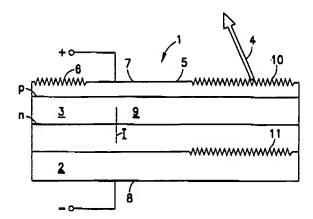
It would have been obvious to one of ordinary skill in the art at the time of the invention to incorporate the teachings of '824 into the device of '490 and '265 by making a grating in the microcavity disk resonator a DFB grating for at least the purpose of

Application/Control Number: 10/736,602

Art Unit: 2828

controlling the spectral bandwidth and wavelength of the output.

Claim 20 is rejected under 35 U.S.C. 103(a) as being unpatentable over '490 and '265 as applied to claim 1 above, and further in view of Portnoi et al. (6,219,369) hereinafter '369.



Regarding **claim 20**, '490 and '265 disclose a grating-outcoupled microcavity disk resonator as described above, but do not disclose that the grating is formed of two gratings, one in the top cladding layer and the other one in the bottom cladding layer. However, Fig 1 of '369 discloses: "wherein the grating region [10, 11] is formed in both a top cladding layer [p-type layer] and a bottom cladding layer[n-type layer] of the resonator [1].

It would have been obvious to one of ordinary skill in the art at the time of the invention to incorporate the teachings of '369 into the device of '490 and '265 by positioning the grating in both the top and the bottom cladding layer for at least the purpose of providing a distributed feedback and increasing output efficiency of the laser.

Claims 25, 26 and 30 are rejected under 35 U.S.C. 103(a) as being unpatentable over '490 and '265 as applied to claim 1 above.

Regarding claims 25, 26 and 30, '490 and '265 disclose a grating-outcoupled microcavity disk resonator as described above, but do not disclose "that the grating-outcoupled microcavity disk resonator comprises a III-V nitride semiconductor heterostructure formed on a substrate (claim 25); wherein the substrate comprises at least one of sapphire, silicon carbide, GaN, AlGaN, AlN, and silicon (claim 26); wherein the grating-outcoupled microcavity disk resonator comprises a heterostructure formed

Application/Control Number: 10/736,602 Page 5

Art Unit: 2828

using at least one of ZnSe, CdS, MgS, MgSe, CdSe, CdTe, ZnO, and MgO" (claim 30).

However, these materials/elements are well known in the art of lasers.

It would have been obvious to one or ordinary skill in the art at the time the of the invention to make the laser of these known materials/elements, since it has been held to be within the general skill of a worker in the art to select a known material/element on the basis of it's suitability for the intended use as a matter of obvious design choice. *In re Leshin*, 227 F.2d 197, 125 USPQ 416 (CCPA 1960).

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Art Unit: 2828

Contact Info

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Marcia A. Golub whose telephone number is 571-272-8602. The examiner can normally be reached on M-F 9-6 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Minsun Harvey can be reached on 571-272-1835. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Marcia A. Golub Assistant Examiner Art Unit 2828 Minsun Harvey Supervisor Art Unit 2828

MAG